## NSN 5961-01-364-2648



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-364-2648 **Inclosure Material:** Metal **Overall Length:** Between 0.960 inches and 0.990 inches **Overall Height:** Between 0.150 inches and 0.180 inches Overall Width: Between 0.720 inches and 0.730 inches **End Application:** E3-havequikan **Mounting Facility Quantity: Internal Configuration:** Field effect **Mounting Method:** Unthreaded hole **Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 1.0 gate to source threshold voltage and 6.0 gate to source threshold voltage **Current Rating Per Characteristic:** 1.00 microamperes reverse gate current with all other terminals short-circuit to source, junction-gate **Power Rating Per Characteristic:** 55.0 watts on-state power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure:** 

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**Demilitarization:**